



ESD



TVS



MOS



LDO



Diode



Sensor



DC-DC

## Product Specification

▶ Domestic Part Number	EVBSS84-S1
▶ Overseas Part Number	BSS84
▶ Equivalent Part Number	BSS84

"S1" means SOT-23

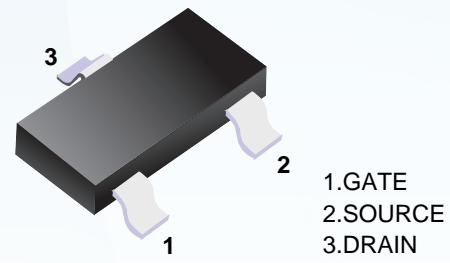


EV is the abbreviation of name EVVO

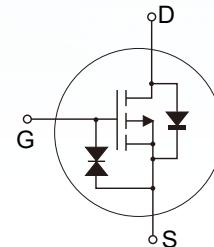
## ■ P-Channel MOSFET

## ■ Features

- Energy efficient
- Low threshold voltage
- High-speed switching
- Miniature surface mount package saves board space
- ESD protected(HBM) up to 2KV



■ Simplified outline(SOT-23)



## ■ Absolute Maximum Ratings Ta = 25°C

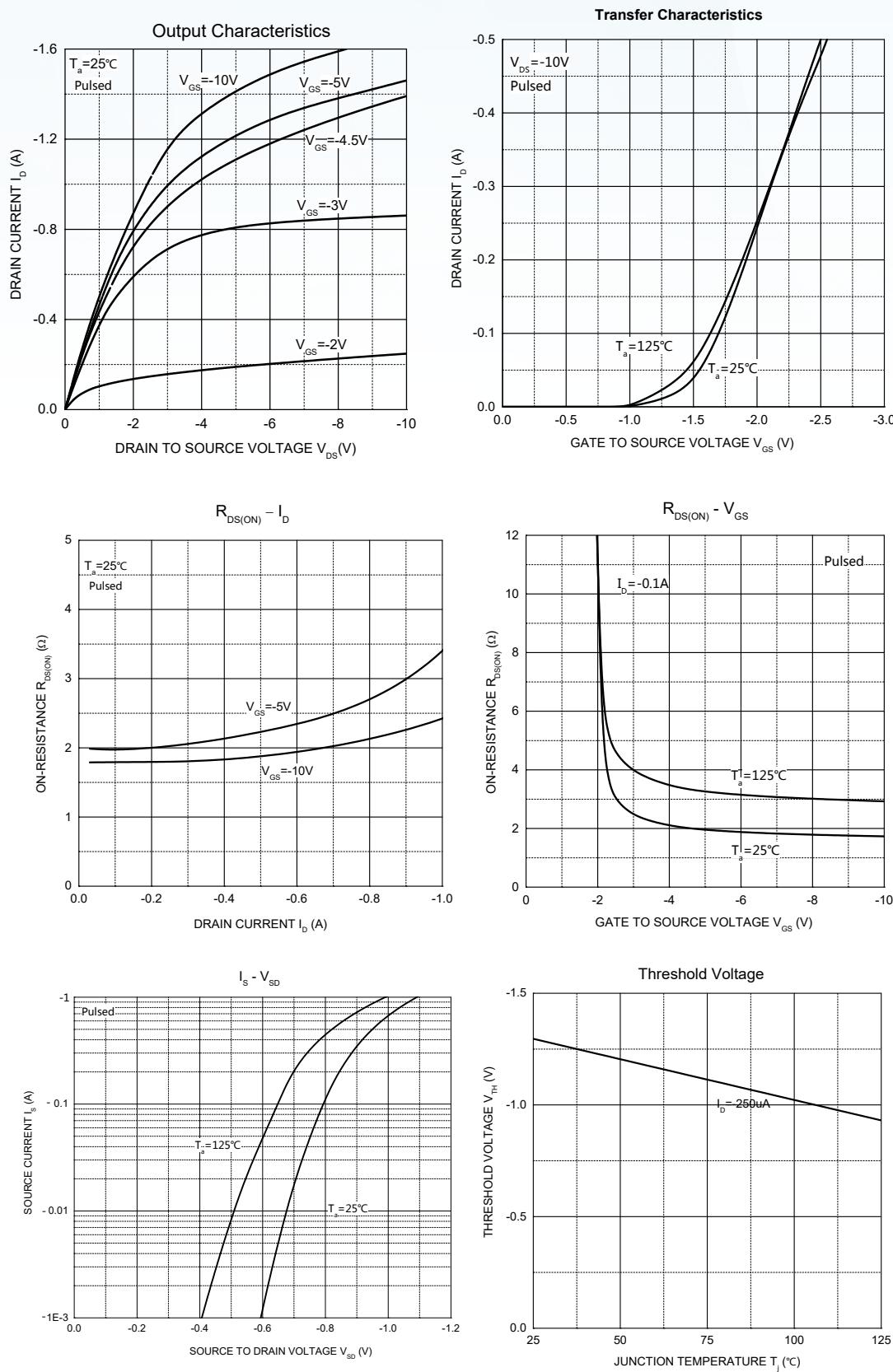
Parameter	Symbol	Maximum	Units
Drain-Source Voltage	-V <sub>DS</sub>	50	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Continuous Drain Current	-I <sub>D</sub>	0.13	A
Pulsed Drain Current <sup>Note1</sup> @tp<10μs	-I <sub>DM</sub>	0.52	
Power Dissipation	P <sub>D</sub>	225	mW
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	150, -55 to 150	°C
<b>Thermal Characteristics</b>			
Parameter	Symbol	Typ.	Units
Maximum Junction-to-Ambient <sup>Note2</sup>	R <sub>θJA</sub>	556	°C/W

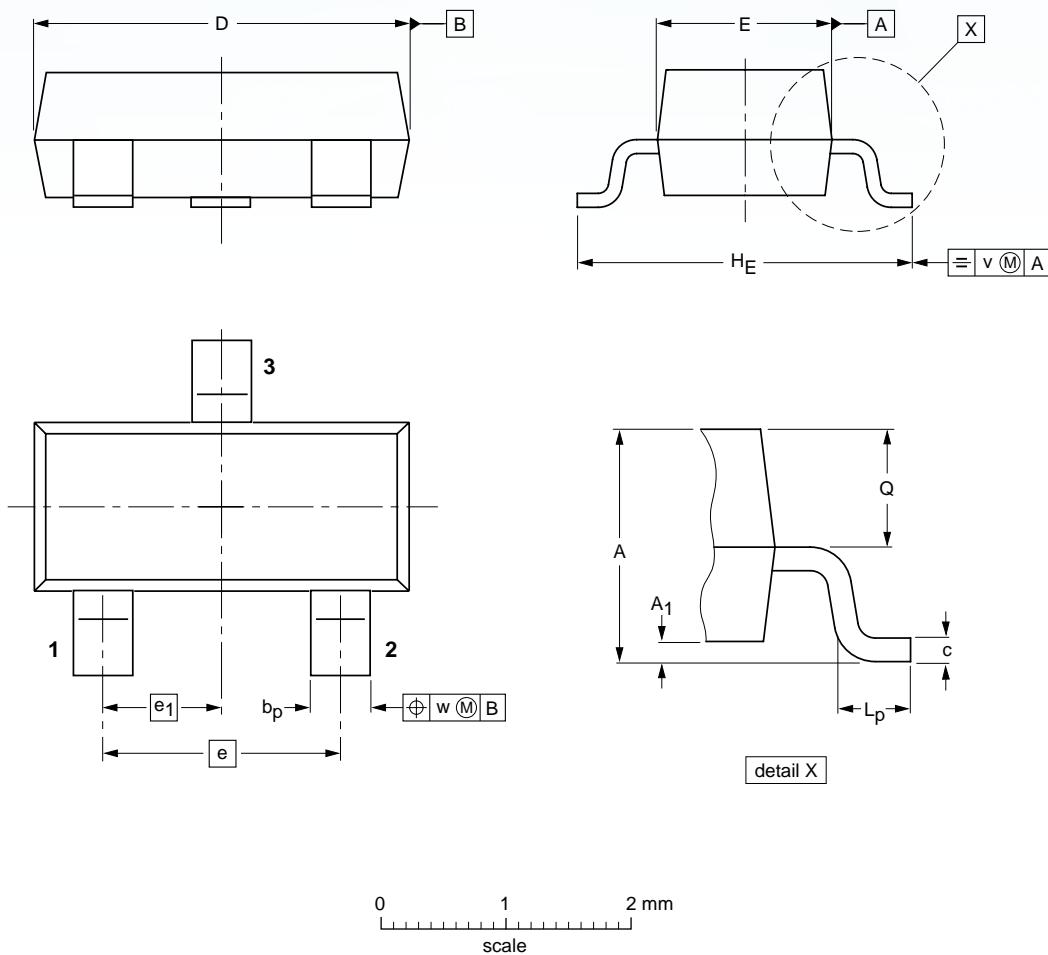
## ■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
<b>Static Parameters</b>						
Drain-Source Breakdown Voltage	-BV <sub>DSS</sub>	-I <sub>D</sub> =250μA, V <sub>GS</sub> =0V	50	--	--	V
Zero Gate Voltage Drain Current	-I <sub>DSS</sub>	-V <sub>DS</sub> =50V, V <sub>GS</sub> =0V	--	--	1	μA
		-V <sub>DS</sub> =25V, V <sub>GS</sub> =0V	--	--	0.1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V	--	1	5	μA
Gate Threshold Voltage <sup>Note3</sup>	-V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , -I <sub>D</sub> =250μA	0.9	1.3	2	V
Static Drain-Source On-Resistance <sup>Note3</sup>	R <sub>DS(ON)</sub>	-V <sub>GS</sub> =10V, -I <sub>D</sub> =0.1A	--	1.7	8	Ω
		-V <sub>GS</sub> =5V, -I <sub>D</sub> =0.1A	--	1.9	10	Ω
Body Diode Forward Voltage	-V <sub>SD</sub>	-I <sub>S</sub> =0.13A, V <sub>GS</sub> =0V	--	--	1.2	V
<b>Dynamic Parameters</b>						
Forward Transconductance <sup>Note3</sup>	g <sub>FS</sub>	-V <sub>DS</sub> =25V, -I <sub>D</sub> =0.1A	50	--	--	mS
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> =0V, -V <sub>DS</sub> =5V, f=1MHz	--	30	--	pF
Output Capacitance	C <sub>oss</sub>		--	10	--	pF
Reverse Transfer Capacitance	C <sub>rss</sub>		--	5	--	pF
<b>Switching Parameters</b>						
Turn-On DelayTime	t <sub>D(on)</sub>	-V <sub>DD</sub> =15V, R <sub>L</sub> =50Ω, -I <sub>D</sub> =2.5A	--	2.5	--	ns
Turn-On Rise Time	t <sub>r</sub>		--	1	--	ns
Turn-Off DelayTime	t <sub>D(off)</sub>		--	16	--	ns
Turn-Off Fall Time	t <sub>f</sub>		--	8	--	ns
<b>Source-Drain Diode characteristics</b>						
Diode forward current	-I <sub>s</sub>		--	--	0.13	A
Diode pulsed forward current	-I <sub>SM</sub>		--	--	0.52	A

Notes: 1. Repetitive rating : Pulse width limited by junction temperature.

2. Surface mounted on FR4 board , t≤10s.
3. Pulse Test : Pulse Width≤300μs, Duty Cycle≤2%.



**■ SOT-23**


DIMENSIONS (mm are the original dimensions)

UNIT	A	$A_1$ max.	$b_p$	c	D	E	e	$e_1$	$H_E$	$L_p$	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

## Disclaimer

EVVOSEMI ("EVVO") reserves the right to make corrections, enhancements, improvements, and other changes to its products and services at any time, and to discontinue any product or service without notice.

EVVO warrants the performance of its hardware products to the specifications applicable at the time of sale in accordance with its standard warranty. Testing and other quality control techniques are used as deemed necessary by EVVO to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

Customers should obtain and confirm the latest product information and specifications before final design, purchase, or use. EVVO makes no warranty, representation, or guarantee regarding the suitability of its products for any particular purpose, nor does EVVO assume any liability for application assistance or customer product design. EVVO does not warrant or accept any liability for products that are purchased or used for any unintended or unauthorized application.

EVVO products are not authorized for use as critical components in life support devices or systems without the express written approval of EVVOSEMI.

The EVVO logo and EVVOSEMI are trademarks of EVVOSEMI or its subsidiaries in relevant jurisdictions. EVVO reserves the right to make changes without further notice to any products herein.